



#### 20V P-Channel Enhancement Mode MOSFET - ESD Protected

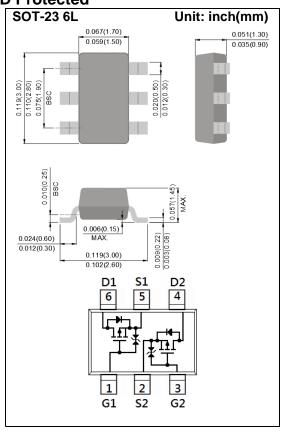
Voltage -20 V Current -500mA

#### **Features**

- Low Voltage Drive (1.2V).
- Advanced Trench Process Technology
- Specially Designed for Load switch, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.0141 grams
- Marking: SG5



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-20	V
Gate-Source Voltage		V <sub>G</sub> s	<u>+</u> 10	V
Continuous Drain Current		ID	-500	mA
Pulsed Drain Current(Note 4)		I <sub>DM</sub>	-1000	mA
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	500	mW
	Derate above 25°C		4	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup>		ReJA	250	°C/W





### **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.3	-0.59	-1.0	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-500mA	-	0.85	1.2	Ω
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-200mA	-	0.98	1.5	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-100mA	-	1.15	2.2	
		V <sub>GS</sub> =-1.5V, I <sub>D</sub> =-50mA	-	1.33	3.6	
		V <sub>GS</sub> =-1.2V, I <sub>D</sub> =-10mA	-	1.5	6.0	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-16V, V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	Igss	V <sub>GS=<u>+</u>8V, V<sub>DS</sub>=0V</sub>	-	<u>+</u> 2	<u>+</u> 10	uA
Dynamic <sup>(Note 5)</sup>						
Total Gate Charge	$Q_g$	$V_{DS}$ =-10V, $I_{D}$ =-500mA, $V_{GS}$ =-4.5V <sup>(Note 1,2)</sup>	-	1.4	-	nC
Gate-Source Charge	$Q_{gs}$		-	0.19	-	
Gate-Drain Charge	$Q_{gd}$		-	0.2	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	38	-	pF
Output Capacitance	Coss		-	15	-	
Reverse Transfer Capacitance	Crss		-	9	-	
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}\text{=-}10\text{V}, I_{D}\text{=-}500\text{mA},$ $V_{GS}\text{=-}4.5\text{V},$ $R_{G}\text{=-}6\Omega^{(Note\ 1,2)}$	-	7.2	-	ns
Turn-On Rise Time	tr		-	21	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	85	-	
Turn-Off Fall Time	tf		-	116	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	,				500	m ^
Diode Forward Current	Is		-	-	-500	mA
Diode Forward Voltage	V <sub>SD</sub>	Is=-500mA, V <sub>GS</sub> =0V	-	-0.93	-1.3	<b>V</b>

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





#### TYPICAL CHARACTERISTIC CURVES

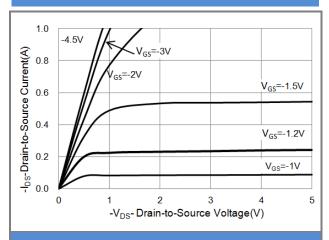


Fig.1 On-Region Characteristics

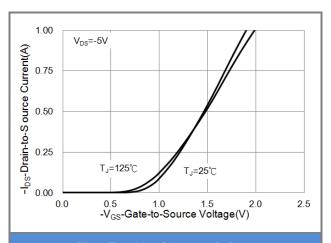


Fig.2 Transfer Characteristics

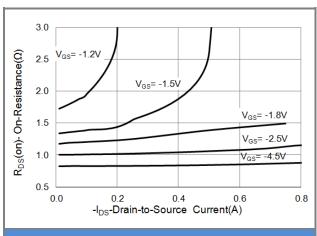


Fig.3 On-Resistance vs. Drain Current

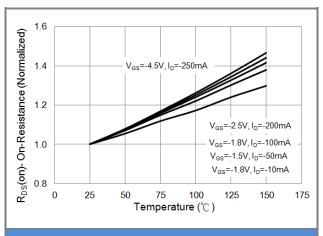


Fig.4 On-Resistance vs. Junction temperature

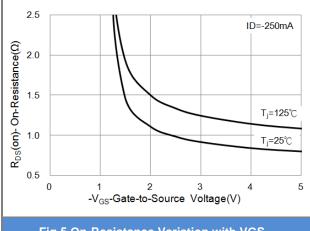
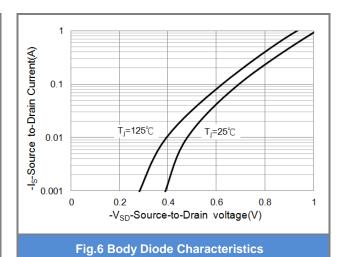


Fig.5 On-Resistance Variation with VGS.

January 20,2022







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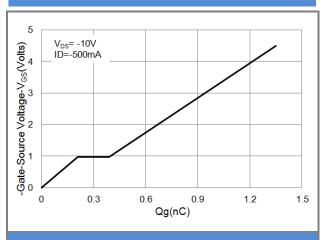


Fig.7 Gate-Charge Characteristics

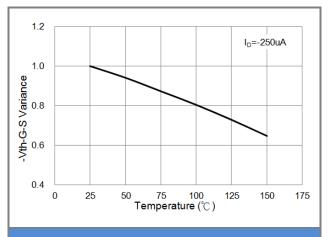


Fig.8 Threshold Voltage Variation with Temperature.

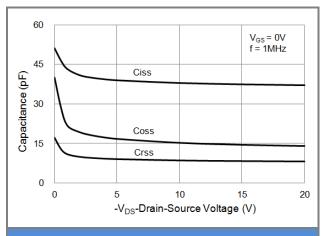


Fig.9 Capacitance vs. Drain-Source Voltage.

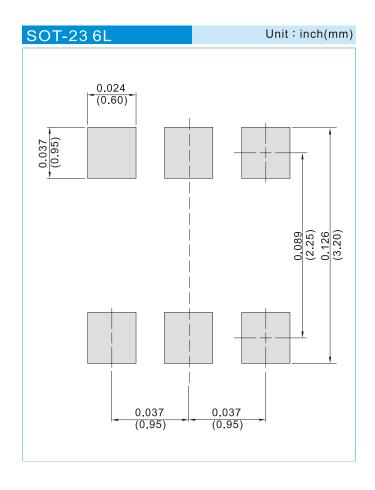




### PART NO. PACKING CODE VERSION

PART NO. PACKING CODE	Package Type	Packing Type	Marking	Version
PJS6835_S1_00001	SOT-23 6L	3K pcs / 7" reel	SG5	Halogen free RoHS compliant
PJS6835_S2_00001	SOT-23 6L	10K pcs / 13" reel	SG5	Halogen free RoHS compliant

### **MOUNTING PAD LAYOUT**







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